

TOSHIBA Field-Effect Transistor Silicon P-Channel MOS Type (U-MOSVI)

# SSM3J130TU

○ Power Management Switch Applications

- 1.5 V drive
- Low ON-resistance:  $R_{DS(ON)} = 63.2 \text{ m}\Omega$  (max) (@ $V_{GS} = -1.5 \text{ V}$ )  
 $R_{DS(ON)} = 41.1 \text{ m}\Omega$  (max) (@ $V_{GS} = -1.8 \text{ V}$ )  
 $R_{DS(ON)} = 31.0 \text{ m}\Omega$  (max) (@ $V_{GS} = -2.5 \text{ V}$ )  
 $R_{DS(ON)} = 25.8 \text{ m}\Omega$  (max) (@ $V_{GS} = -4.5 \text{ V}$ )

**Absolute Maximum Ratings (Ta = 25°C)**

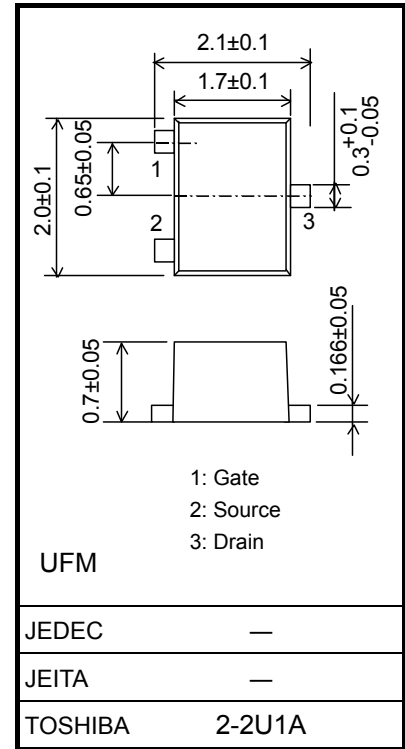
| Characteristic            | Symbol         | Rating     | Unit |
|---------------------------|----------------|------------|------|
| Drain-Source voltage      | $V_{DSS}$      | -20        | V    |
| Gate-Source voltage       | $V_{GSS}$      | $\pm 8$    | V    |
| Drain current             | DC             | $I_D$      | -4.4 |
|                           | Pulse          | $I_{DP}$   | -8.8 |
| Drain power dissipation   | $P_D$ (Note 1) | 800        | mW   |
|                           | $P_D$ (Note 2) | 500        |      |
| Channel temperature       | $T_{ch}$       | 150        | °C   |
| Storage temperature range | $T_{stg}$      | -55 to 150 | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Mounted on a ceramic board.  
 (25.4 mm × 25.4 mm × 0.8 mm, Cu Pad: 645 mm<sup>2</sup>)
- Note 2: Mounted on an FR4 board.  
 (25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm<sup>2</sup>)

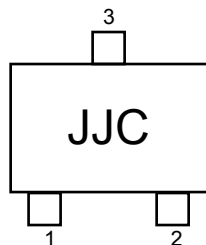
Unit: mm



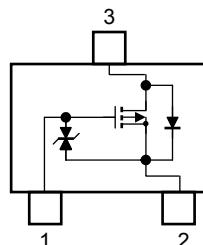
Weight: 6.6 mg (typ.)

|         |        |
|---------|--------|
| JEDEC   | —      |
| JEITA   | —      |
| TOSHIBA | 2-2U1A |

**Marking**



**Equivalent Circuit (top view)**



## Electrical Characteristics (Ta = 25°C)

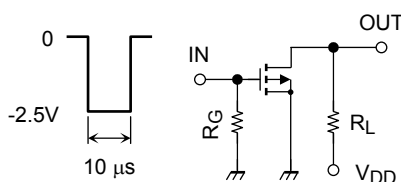
| Characteristic                 | Symbol        | Test Conditions   | Min   | Typ. | Max     | Unit          |    |
|--------------------------------|---------------|---|---|------|---------|---------------|----|
| Drain-Source breakdown voltage | $V_{(BR)DSS}$ | $I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$                                     | -20   | —    | —       | V             |    |
|                                | $V_{(BR)DSX}$ | $I_D = -1 \text{ mA}, V_{GS} = 5 \text{ V}$ (Note 4)                            | -15   | —    | —       |               |    |
| Drain cut-off current          | $I_{DSS}$     | $V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$                                  | —   | —    | -1      | $\mu\text{A}$ |    |
| Gate leakage current           | $I_{GSS}$     | $V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$                                | —   | —    | $\pm 1$ | $\mu\text{A}$ |    |
| Gate threshold voltage         | $V_{th}$      | $V_{DS} = -3 \text{ V}, I_D = -1 \text{ mA}$                                    | -0.3  | —    | -1.0    | V             |    |
| Forward transfer admittance    | $ Y_{fs} $    | $V_{DS} = -3 \text{ V}, I_D = -2.0 \text{ A}$ (Note 3)                          | 8.8   | 17.5 | —       | S             |    |
| Drain-source ON-resistance     | $R_{DS(ON)}$  | $I_D = -4.0 \text{ A}, V_{GS} = -4.5 \text{ V}$ (Note 3)                        | —   | 20.9 | 25.8    | m $\Omega$    |    |
|                                |               | $I_D = -4.0 \text{ A}, V_{GS} = -2.5 \text{ V}$ (Note 3)                        | —   | 24.2 | 31.0    |               |    |
|                                |               | $I_D = -2.5 \text{ A}, V_{GS} = -1.8 \text{ V}$ (Note 3)                        | —   | 28.8 | 41.1    |               |    |
|                                |               | $I_D = -1.5 \text{ A}, V_{GS} = -1.5 \text{ V}$ (Note 3)                        | —   | 32.4 | 63.2    |               |    |
| Input capacitance              | $C_{iss}$     | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}$<br>$f = 1 \text{ MHz}$           | —   | 1800 | —       | pF            |    |
| Output capacitance             | $C_{oss}$     |   | —   | 205  | —       |               |    |
| Reverse transfer capacitance   | $C_{rss}$     |   | —   | 190  | —       |               |    |
| Switching time                 | Turn-on time  | $t_{on}$  | $V_{DD} = -10 \text{ V}, I_D = -1.5 \text{ A}$<br>$V_{GS} = 0 \text{ to } -2.5 \text{ V}, R_G = 4.7 \Omega$ | —    | 25      | —             | ns |
|                                | Turn-off time | $t_{off}$   |   | —    | 133     | —             |    |
| Total Gate Charge              | $Q_g$         | $V_{DS} = -10 \text{ V}, I_{DS} = -4.4 \text{ A},$<br>$V_{GS} = -4.5 \text{ V}$ | —   | 24.8 | —       | nC            |    |
| Gate-Source Charge             | $Q_{gs}$      |   | —   | 18.0 | —       |               |    |
| Gate-Drain Charge              | $Q_{gd}$      |   | —   | 6.8  | —       |               |    |
| Drain-Source forward voltage   | $V_{DSF}$     | $I_D = 4.4 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 3)                            | —   | 0.83 | 1.2     | V             |    |

Note3: Pulse test

Note4:  $V_{DSX}$  mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

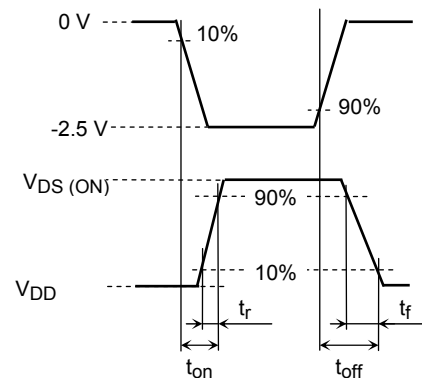
## Switching Time Test Circuit

### (a) Test Circuit



$V_{DD} = -10 \text{ V}$   
 $R_G = 4.7 \Omega$   
 D.U.  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5 \text{ ns}$   
 Common Source  
 $T_a = 25^\circ\text{C}$

### (b) $V_{IN}$



### (c) $V_{OUT}$

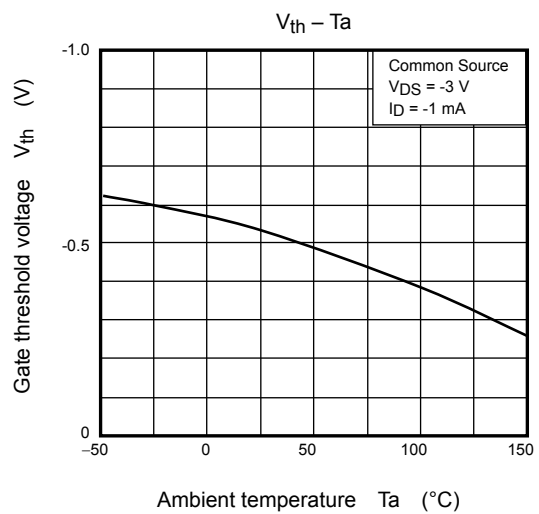
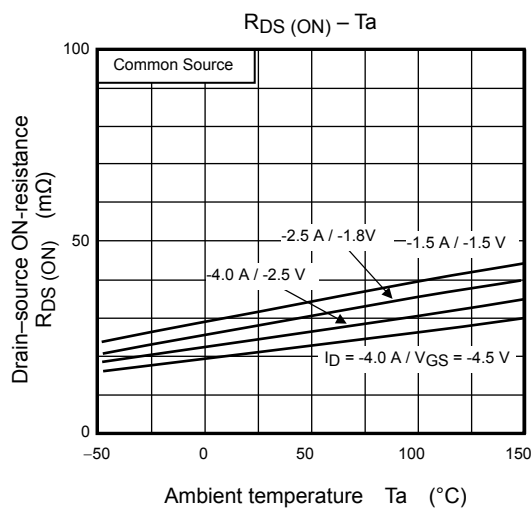
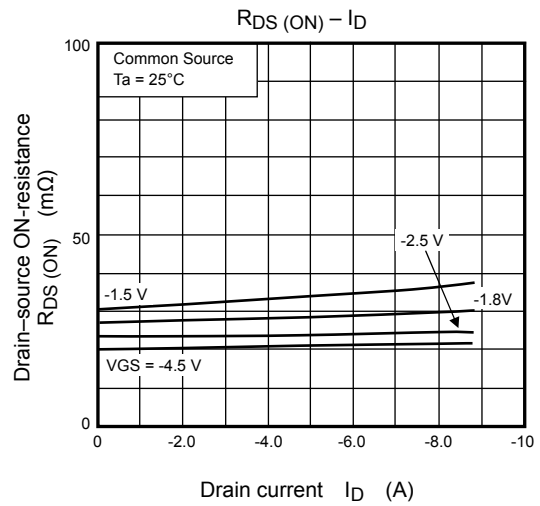
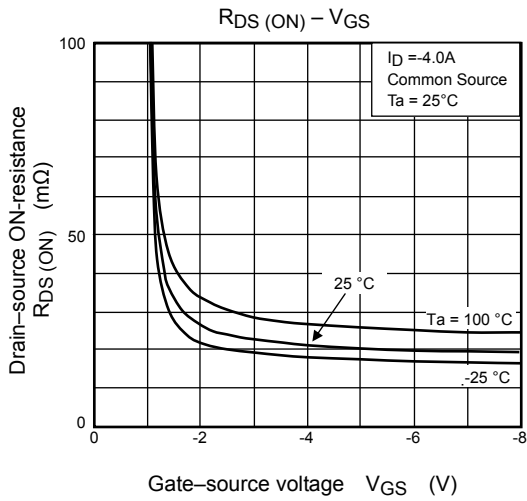
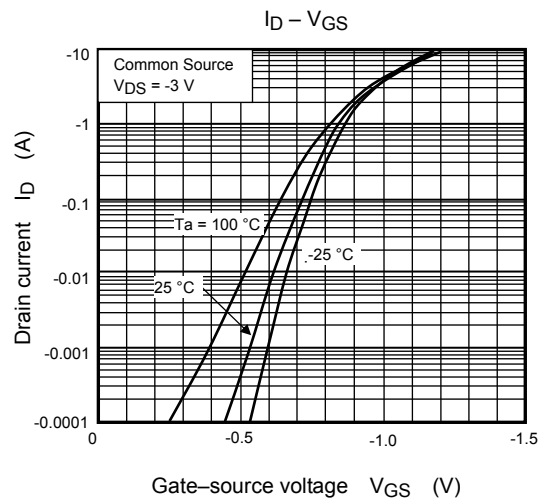
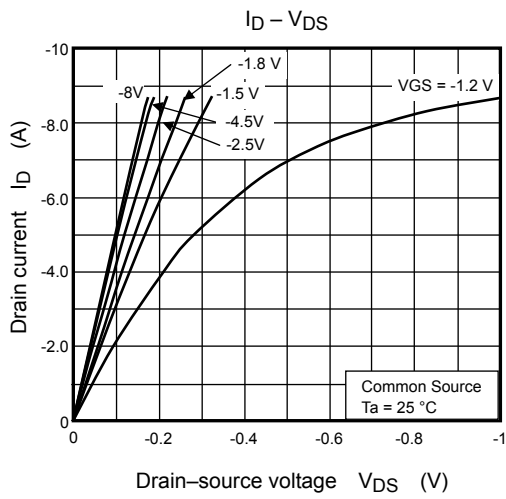
## Usage Considerations

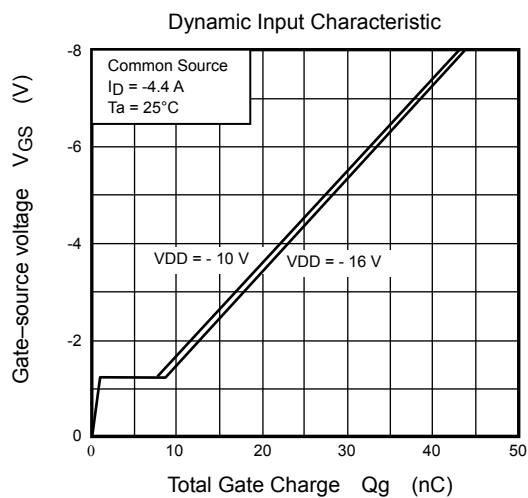
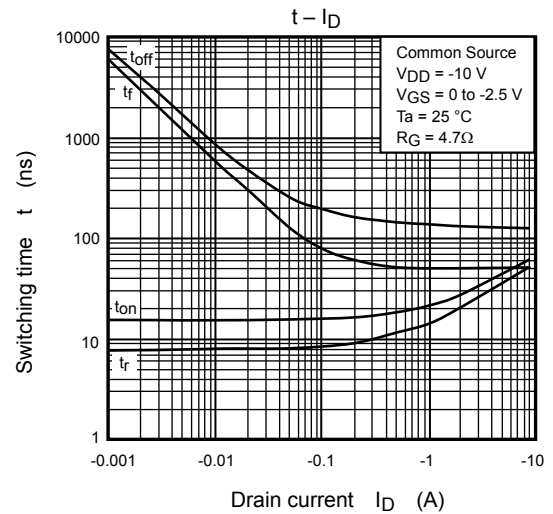
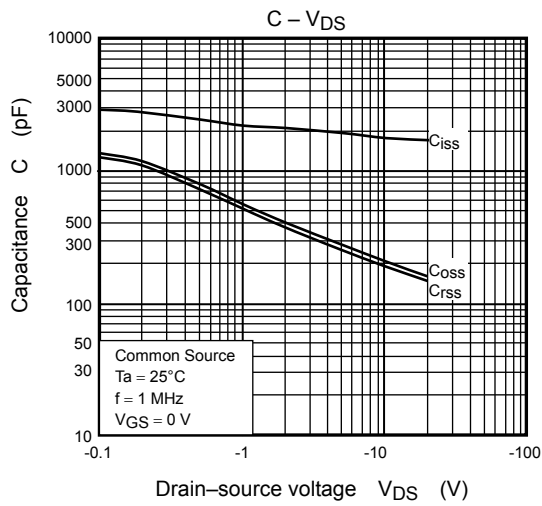
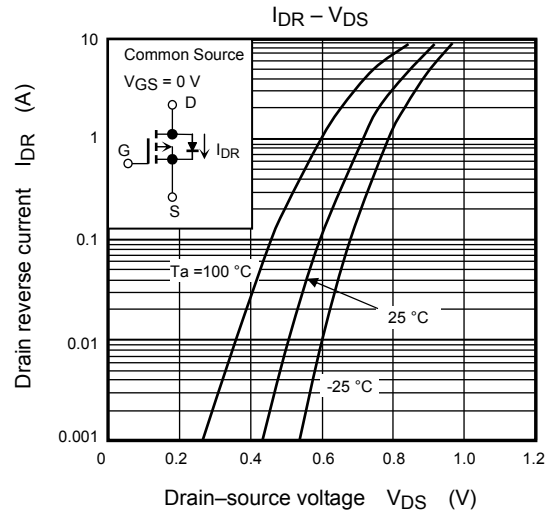
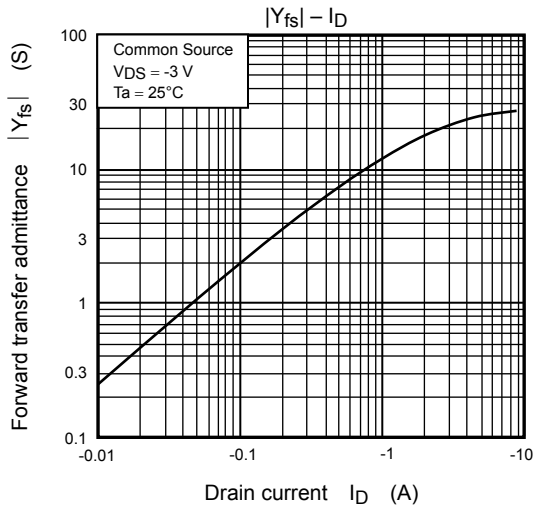
Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to be below  $-1 \text{ mA}$  for the SSM3J130TU. Then, for normal switching operation,  $V_{GS(on)}$  must be higher than  $V_{th}$ , and  $V_{GS(off)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .

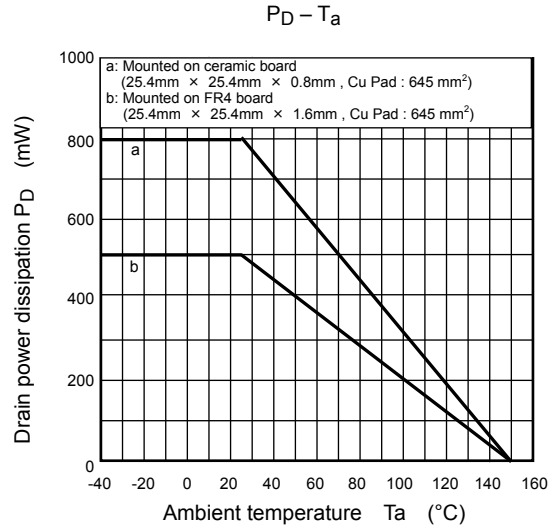
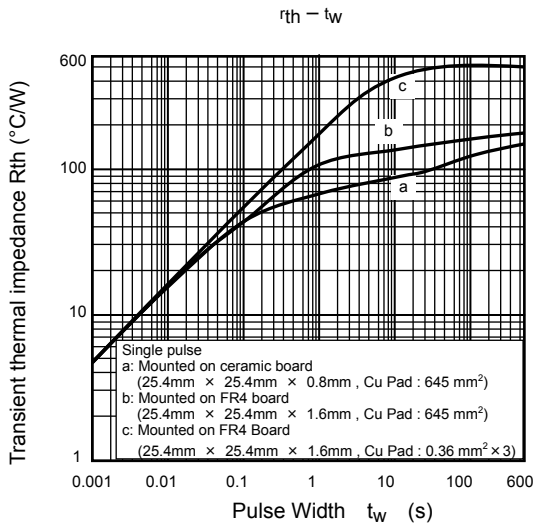
Take this into consideration when using the device.

## Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.







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Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А